

MBRF20H100CT – MBRF20H200CT

Isolated 20.0 AMPS. Schottky Barrier Rectifiers



Features

- ∻ Plastic material used carries Underwriters Laboratory Classifications 94V-0
- ∻ Metal silicon junction, majority carrier conduction
- ∻ Low power loss, high efficiency
- High current capability, low forward voltage drop ∻
- ∻ High surge capability
- For use in low voltage, high frequency inverters, free ∻ wheeling, and polarity protection applications
- ∻ Guardring for overvoltage protection
- ∻ High temperature soldering guaranteed: 260°C/10 seconds,0.25"(6.35mm)from case

Mechanical Data

- ∻ Cases: ITO-220AB molded plastic
- ∻ Terminals: Pure tin plated, lead free. solderable per MIL-STD-750, Method 2026
- ♦ Polarity: As marked
- ∻ Mounting position: Any
- ∻
- Mounting torque: 5 in. Ibs. max Weight: 0.08 ounce, 2.24 grams ♦

Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

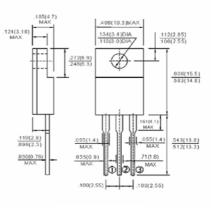
Type Number	Symbol	MBRF 20H100CT	MBRF 20H150CT	MBRF 20H200CT	Units
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	100	150	200	V
Maximum RMS Voltage	V _{RMS}	70	105	140	V
Maximum DC Blocking Voltage	V _{DC}	100	150	200	V
Maximum Average Forward Rectified Current at T_c =133°C	I _(AV)	20			А
Peak Repetitive Forward Current (Rated V _R , Square Wave, 20KHz) at Tc=133°C	I _{FRM}	20			А
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I _{FSM}	150			А
Peak Repetitive Reverse Surge Current (Note 1)	I _{RRM}	1.0 0.5		А	
Maximum Instantaneous Forward Voltage at (Note 2) I _F = 10A, Tc=25°C I _F = 10A, Tc=125°C I _F =20A, Tc=25°C I _F =20A, Tc=125°C	V _F	0.85 0.75 0.95 0.85	0.88 0.75 0.97 0.85		V
Maximum Instantaneous Reverse Current at Rated DC Blocking Voltage @Tc=25 °C @ Tc=125 °C	I _R	5.0 2.0			uA mA
Voltage Rate of Change, (Rated V_R)	dV/dt	10,000			V/uS
$\begin{array}{l} \text{RMS Isolation Voltage (t=1.0 second, R.H.} \\ \leq 30\%, \ T_{\text{A}} = 25 \ ^{\circ}\text{C}) & (\text{Note 4}) \\ & (\text{Note 5}) \\ & (\text{Note 6}) \end{array}$	V _{ISO}	4500 3500 1500			v
Typical Thermal Resistance Per Leg (Note3)	R _{θJC}	3.5			°C/W
Operating Junction Temperature Range	TJ	-65 to +175			°C
Storage Temperature Range	TSTG	-65 to +175			°C
Notes: 1. 2.0 us Pulse Width, f=1.0 KHz		2. Pulse Test: 3	00us Pulse Width	, 1% Duty Cycle	

- 3. Thermal Resistance from Junction to Case Per Leg.
- 4. Clip Mounting (on case), where lead does not overlap heatsink with 0.110" offset.

5. Clip mounting (on case), where leads do overlap heatsink.

6. Screw mounting with 4-40 screw, where washer diameter is \leq 4.9 mm (0.19")







Dimensions in inches and (millimeters)



FIG.1- FORWARD CURRENT DERATING CURVE 2 RESISTIVE OR INDUCTIVE LOAD AVERAGE FORWARD CURRENT. (A) 16 12 8 0 50 75 100 150 25 125 175 CASE TEMPERATURE. (°C) FIG.3- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS PER LEG 40 10 € INSTANTANEOUS FORWARD CURRENT. Tj=125° 0. - w Pı . idth 30 1% Duty Cycle 0.01 0.2 0.3 0.4 0.5 0.6 0.7 0.8 0.9 1.0 1.1 1.2 0.1 0 FORWARD VOLTAGE. (V) FIG.5- TYPICAL JUNCTION CAPACITANCE PER LEG 5,000

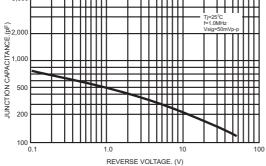
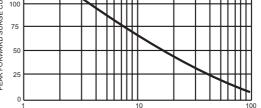


FIG.2- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT PER LEG 150 Т Tj=Tj max. 8.3ms Single Half Sine Wave JEDEC Method € PEAK FORWARD SURGE CURRENT. 125 100

RATINGS AND CHARACTERISTIC CURVES(MBRF20H100CT - MBRF20H200CT)

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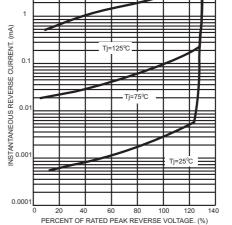
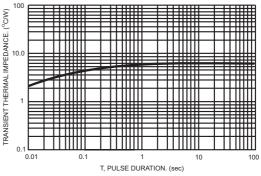


FIG.6- TYPICAL TRANSIENT THERMAL IMPEDANCE PER LEG



Version: A07